

AMENDMENT

Serial Number: 10/043065

Filing Date: January 9, 2002

Title: P-CHANNEL DYNAMIC FLASH MEMORY CELLS WITH ULTRATHIN TUNNEL OXIDES

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Dkt: 303.684US3

IN THE DRAWINGS

Figure 5B is amended to remove an equation. Applicant has amended the specification to add the deleted equation. A complete set of Formal Drawings is enclosed herewith.

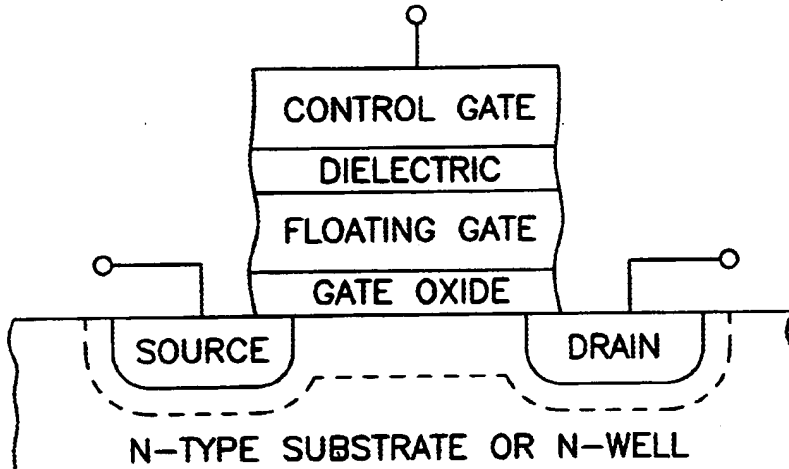


FIG. 1A
(PRIOR ART)
PMOS

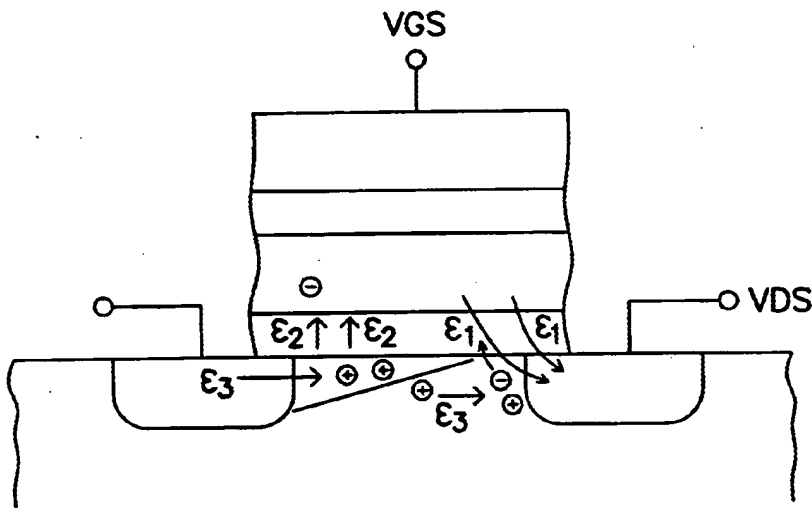


FIG. 1B
(PRIOR ART)

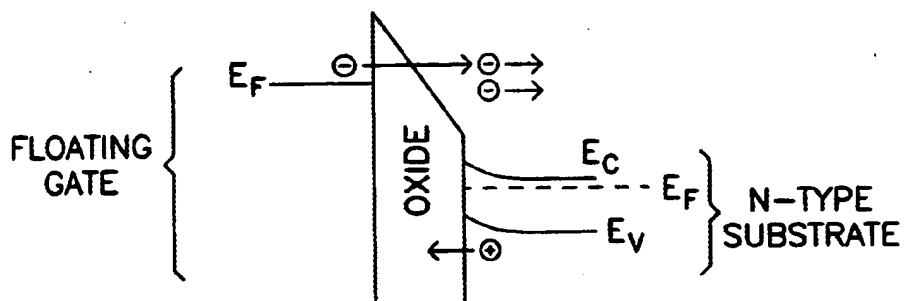


FIG. 2A
(PRIOR ART)

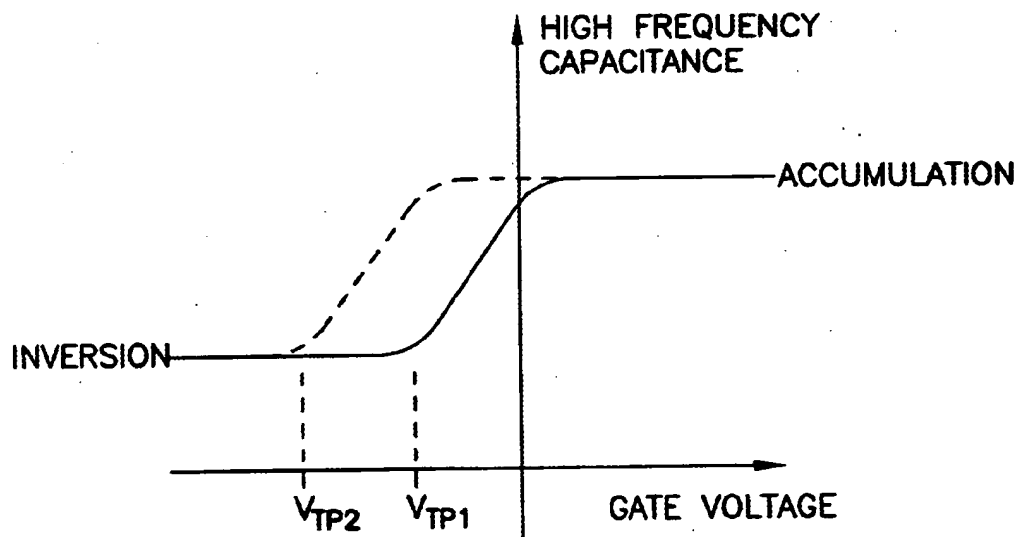


FIG. 2B
(PRIOR ART)



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YNAMIC FLASH MEMORY CELLS WITH ULTRATHIN TUNN OXIDES

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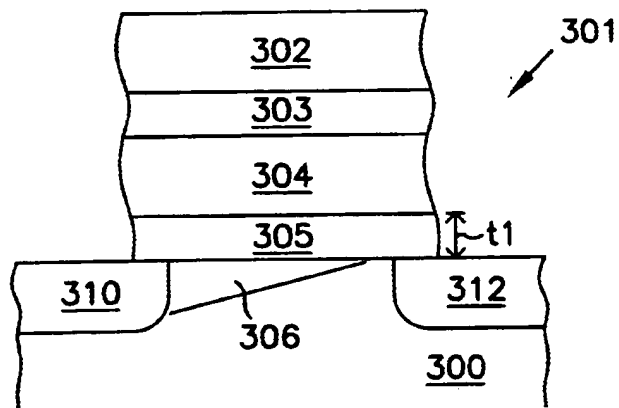


FIG. 3A

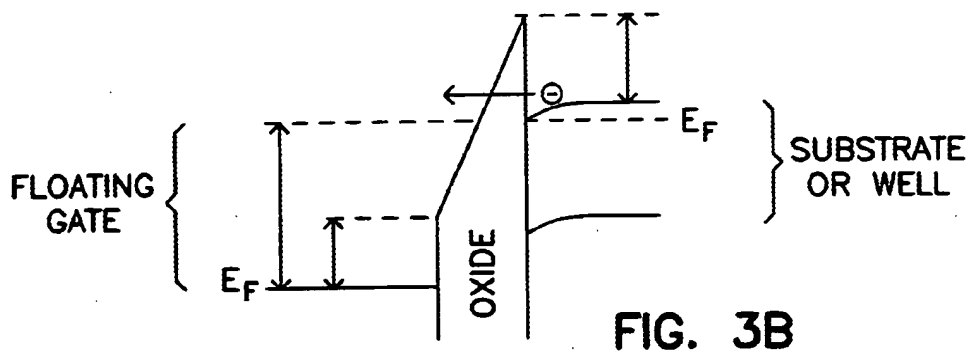


FIG. 3B

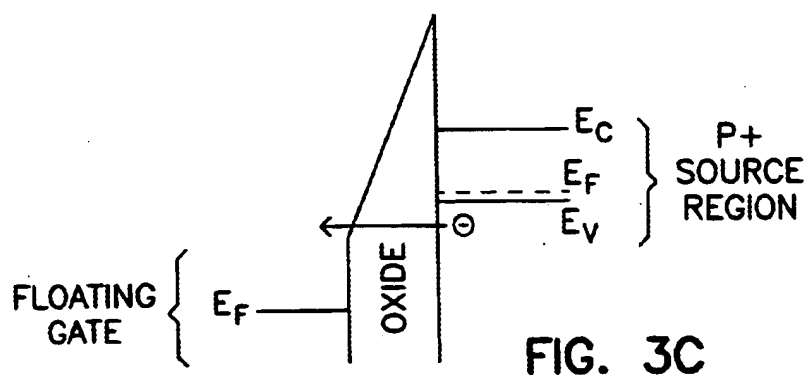


FIG. 3C

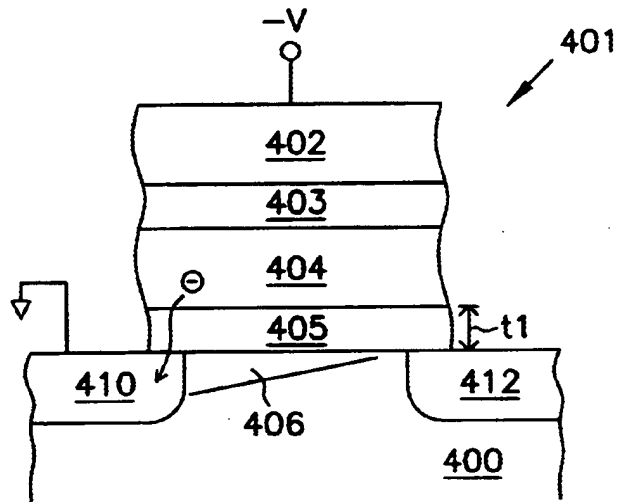


FIG. 4A

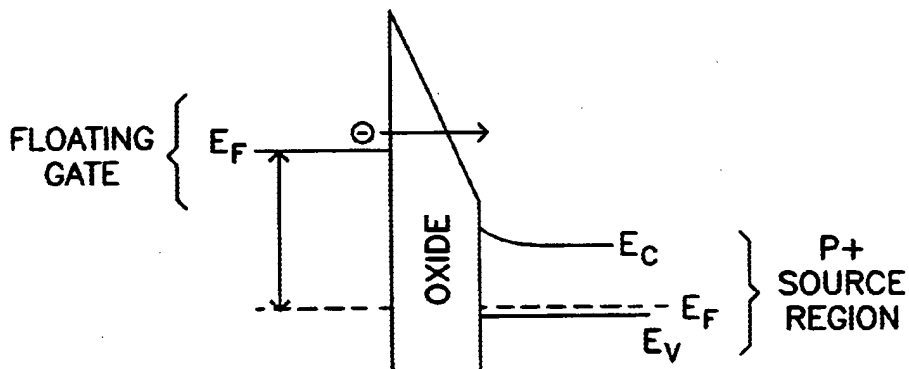


FIG. 4B

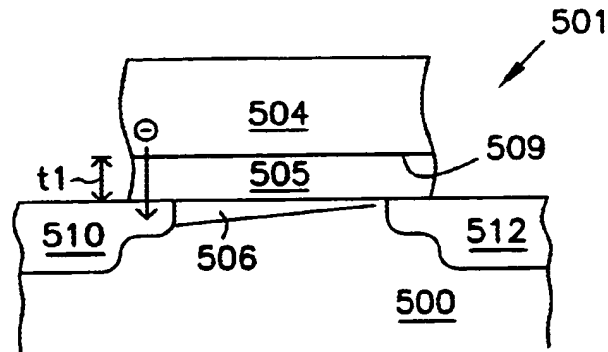
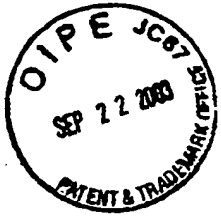


FIG. 5A

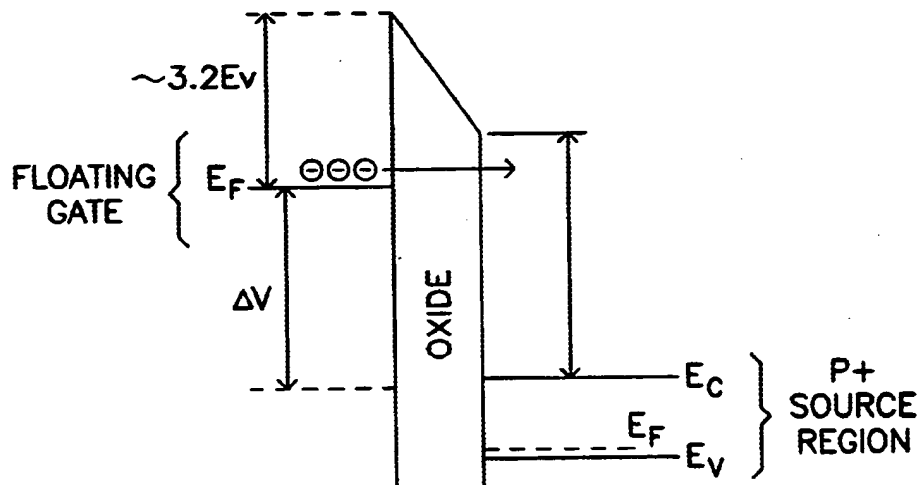
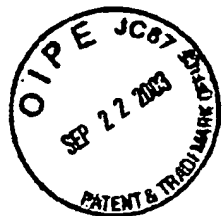


FIG. 5B



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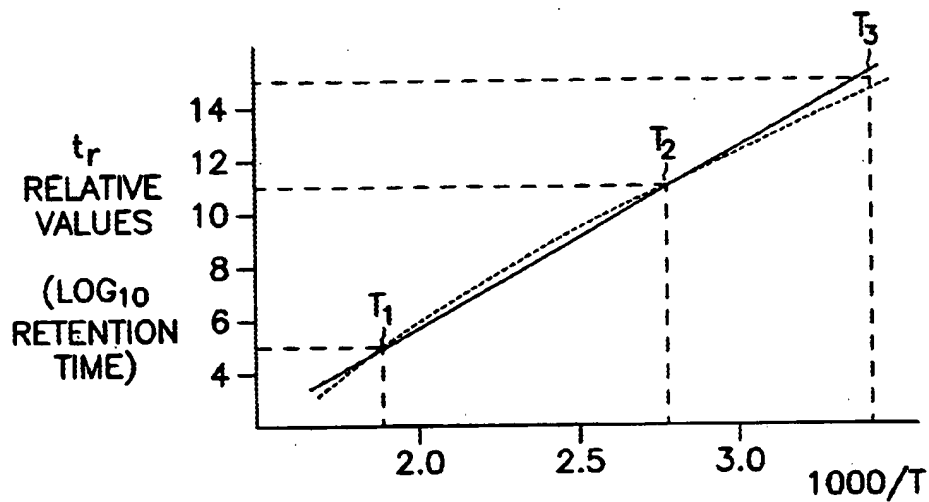


FIG. 6A

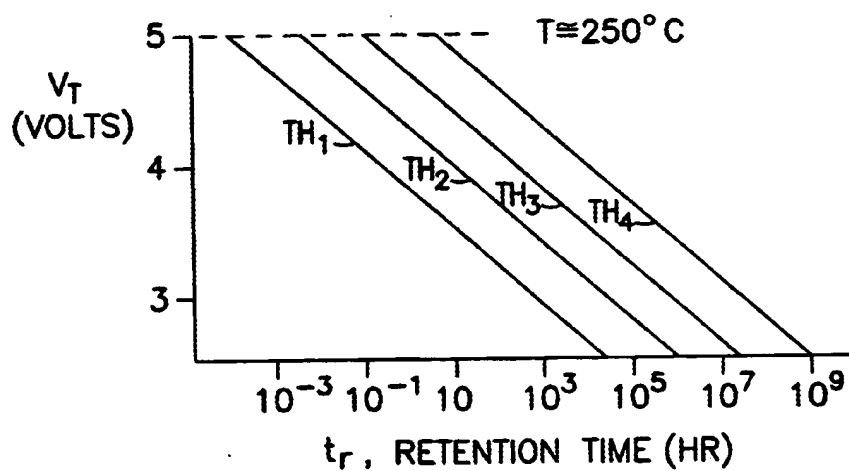
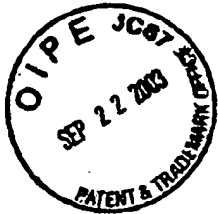


FIG. 6B



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XIDES

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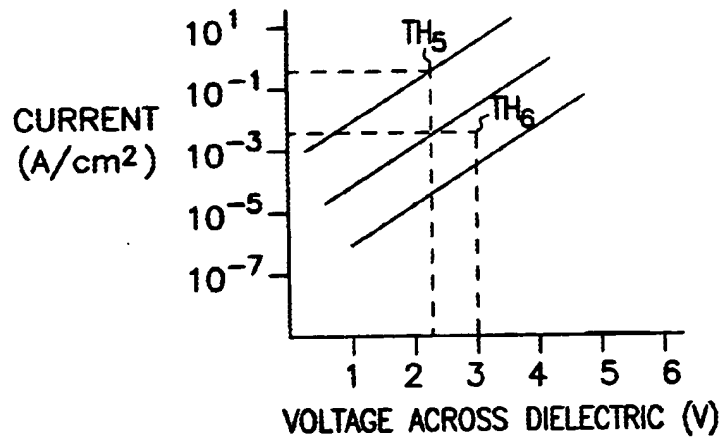


FIG. 7

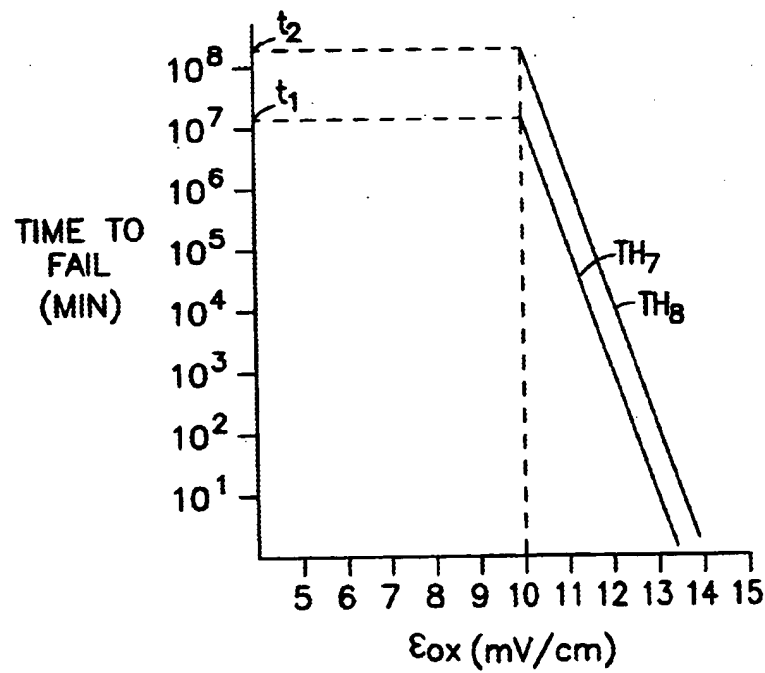
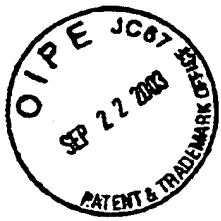


FIG. 8



TITLE: P-CHAN

YNAMIC FLASH MEMORY CELLS WITH ULTRATHIN TUNN OXIDES

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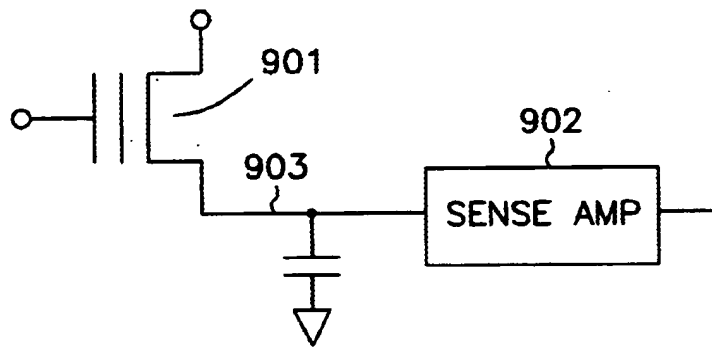


FIG. 9

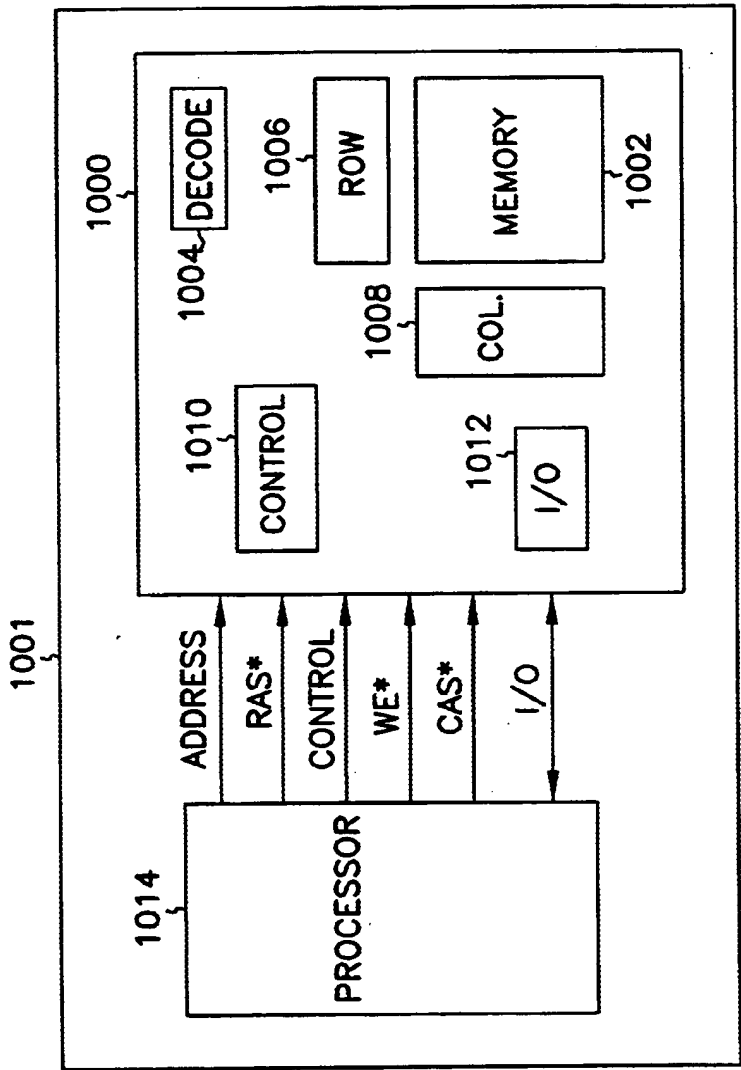


FIG. 10



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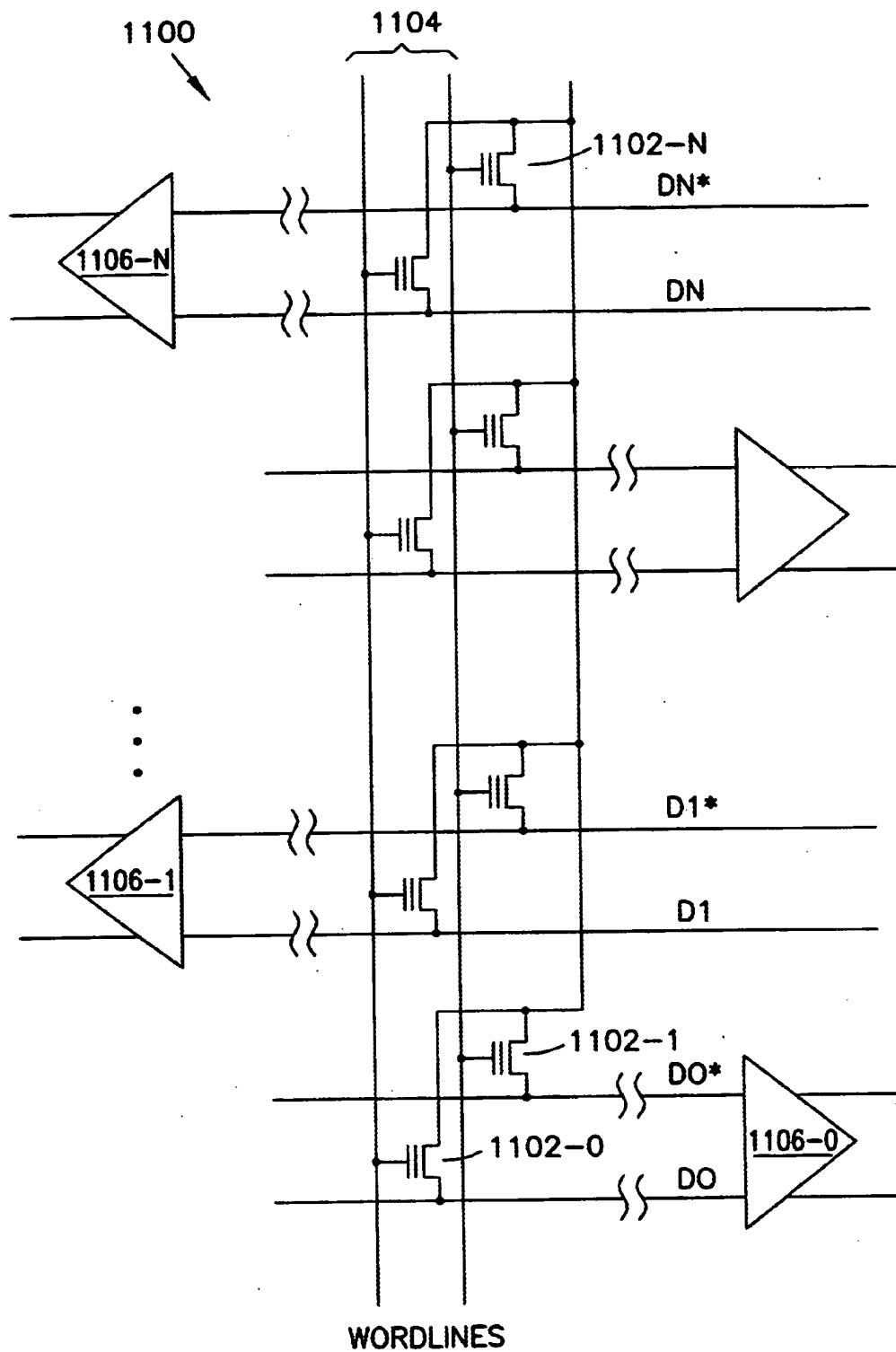


FIG. 11